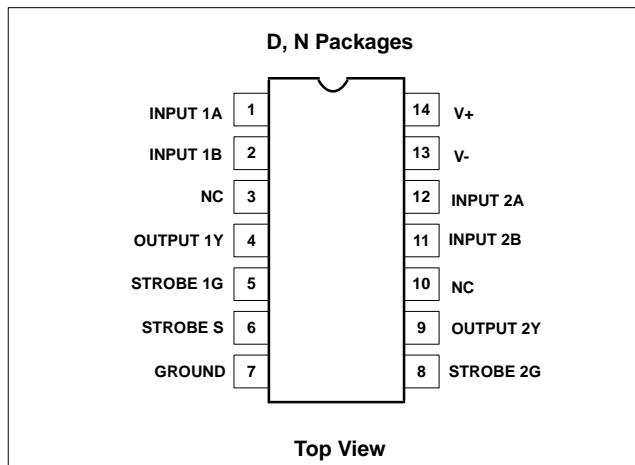
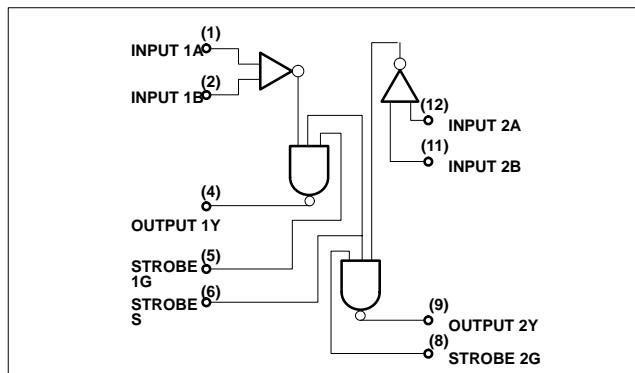


High-speed dual-differential comparator/sense amp**NE522****FEATURES**

- 15ns maximum guaranteed propagation delay
- 20 μ A maximum input bias current
- TTL-compatible strobes and outputs
- Large common-mode input voltage range
- Operates from standard supply voltages

APPLICATIONS

- MOS memory sense amp
- A-to-D conversion
- High-speed line receiver

PIN CONFIGURATION**BLOCK DIAGRAM****ORDERING INFORMATION**

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
14-Pin Plastic DIP	0 to +70°C	NE522N	0405B
14-Pin Plastic SO	0 to +70°C	NE522D	0175D

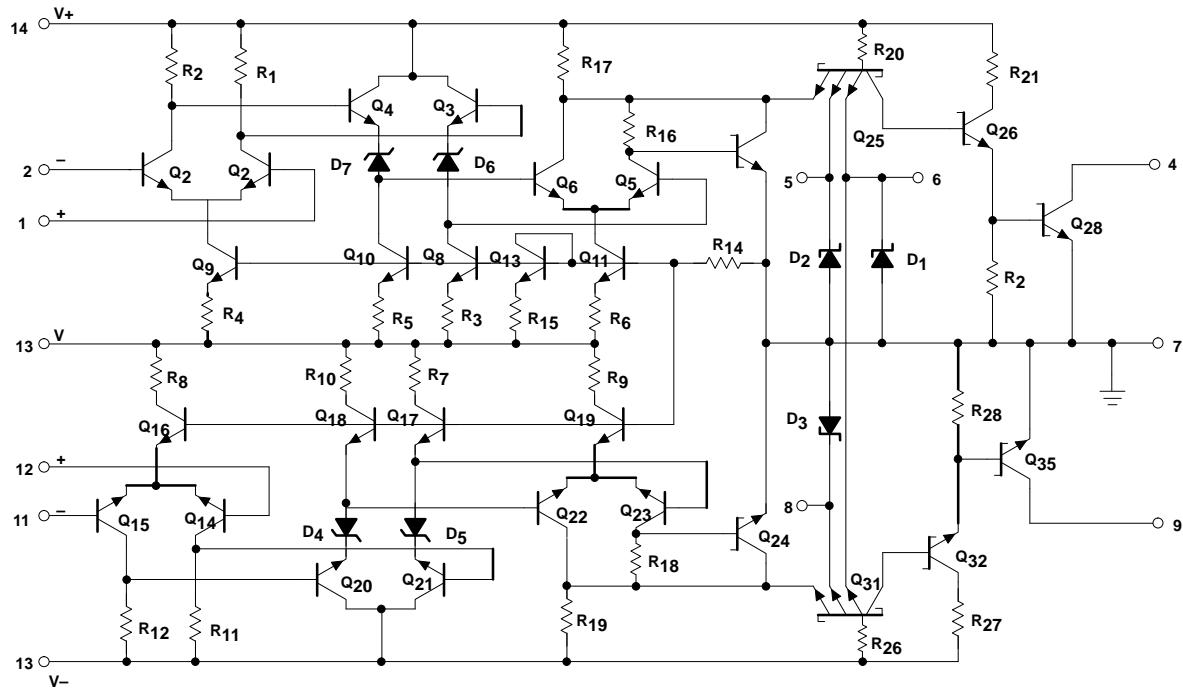
ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNITS
V+	Single supply voltage Positive	+7	V
V-	Negative	-7	V
V _{IDR}	Differential input voltage	± 6	V
V _{IN}	Input voltage Common-mode	± 5	V
	Strobe/gate	+5.25	V
P _D	Power dissipation	600	mW
T _A	Operating temperature range NE522	0 to 70	°C
T _{STG}	Storage temperature range	-65 to +150	°C
T _{SOLD}	Lead soldering temperature (10sec max)	+300	°C

High-speed dual-differential comparator/sense amp

NE522

EQUIVALENT SCHEMATIC



High-speed dual-differential comparator/sense amp

NE522

DC ELECTRICAL CHARACTERISTICS $V_{\pm} = \pm 5V \pm 5\%$, $T_A = 0$ to $+70^{\circ}\text{C}$, unless otherwise stated.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
V_{OS}	Input offset voltage At 25°C Over temperature range	$V_+ = +4.75V$, $V_- = -4.75V$		6	7.5 10	mV
I_{BIAS}	Input bias current At 25°C Over temperature range	$V_+ = +5.25V$, $V_- = -5.25V$		7.5	20 40	μA
I_{os}	Input offset current At 25°C Over temperature range	$V_+ = +5.25V$, $V_- = -5.25V$		1.0	5 12	μA
V_{CM}	Common-mode voltage range	$V_+ = +4.75V$, $V_- = -4.75V$	-3		+3	V
V_{IL}	Low level input At 25°C Over temperature range				0.8 0.7	V
V_{IH}	High level temperature		2.0			V
I_{IH}	Input current High	$V_+ = +5.25V$, $V_- = -5.25V$ $V_{IH} = 2.7V$ 1G or 2G strobe Common strobe S			50 100	μA μA
I_{IL}	Low input current	$V_{IL} = 0.5V$ 1G or 2G strobe Common strobe S			-2.0 -4.0	mA mA
V_{OL}	Output voltage Low	$V_+ = +5.25V$, $V_- = -5.25V$, $V_{I(S)} = 2.0V$, $I_{LOAD} = 20\text{mA}$			0.5	V
I_{OH}	Output current High	$V_+ = +4.75V$, $V_- = -4.75V$, $V_{OH} = 5.25V$			250	μA
V_+ V_-	Supply voltage Positive Negative		4.75 -4.75	5.0 -5.0	5.25 -5.25	V
I_{CC+} I_{CC-}	Supply current Positive Negative	$V_+ = +5.25V$, $V_- = -5.25V$, $T_A = 25^{\circ}\text{C}$		27 -15	35 -28	mA

High-speed dual-differential comparator/sense amp

NE522

AC ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $R_L = 280\Omega$, $C_L = 15\text{pF}$, unless otherwise stated.

SYMBOL	PARAMETER	FROM INPUT	TO OUTPUT	LIMITS			UNITS
				MIN	TYP	MAX	
I_R	Input resistance				4		$\text{k}\Omega$
I_C	Input capacitance				3		pF
Large-signal switching speed							
$t_{PLH(D)}$	Propagation delay Low to high ¹	Amp	Output		10	15	
$t_{PHL(D)}$	High to low ¹	Amp	Output		8	12	ns
$t_{PLH(S)}$	Low to high ²	Strobe	Output		6	13	
$t_{PHL(S)}$	High to low ²	Strobe	Output		5	9	
f_{MAX}	Maximum operating frequency			25	35		MHz

NOTES:

1. Response time measured from 0V point of +100mV_{P-P} 10MHz square wave to the 1.5V point of the output.
2. Response time measured from 1.5V point of the input to 1.5V point of the output.

LOGIC FUNCTION TABLE

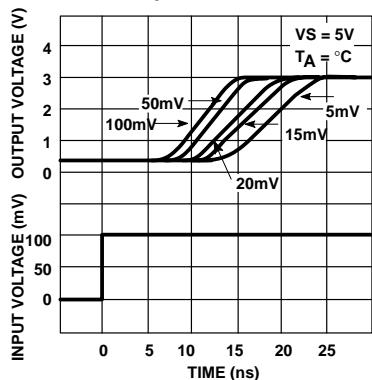
$V_{ID} (A^+, B^-)$	STRS	STRG	OUTPUT TRANSISTOR
$< -V_{OS}$	H	H	ON
$-V_{OS} < V_{ID} < V_{OS}$	H	H	Undefined
$> V_{OS}$	H	H	OFF
X	L	X	OFF
X	X	L	OFF

High-speed dual-differential comparator/sense amp

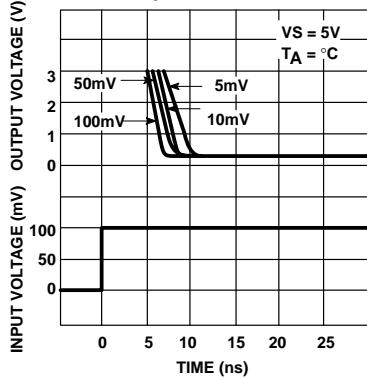
NE522

EQUIVALENT SCHEMATIC

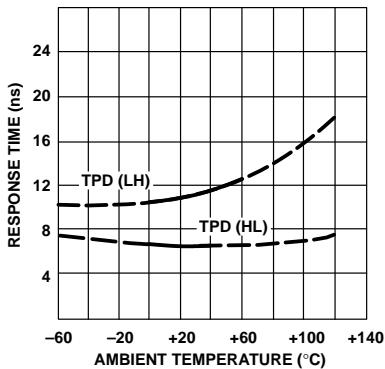
Response Time for Various Input Overdrives



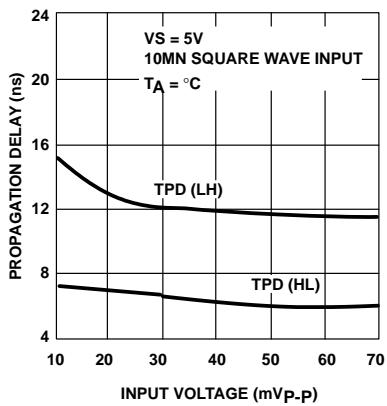
Response Time for Various Input Overdrives



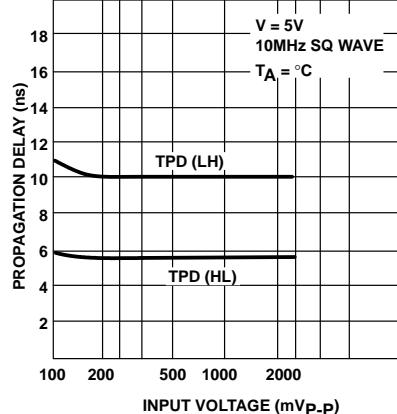
Response Time vs Temperature



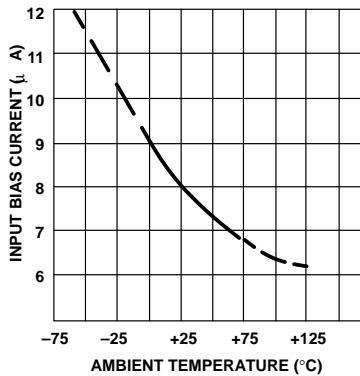
Propagation Delay for Various Input Voltages



Propagation Delay for Various Input Voltages



Input Bias Current vs Ambient Temperature



Input Offset Current vs Ambient Temperature

